Electronic Supplementary Material (ESI) for Physical Chemistry Chemical Physics.

Tuning the carrier concentration using Zintl chemistry in Mg_3Sb_2 and, its implications on thermoelectric figure-of-merit

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Supplementary Information:

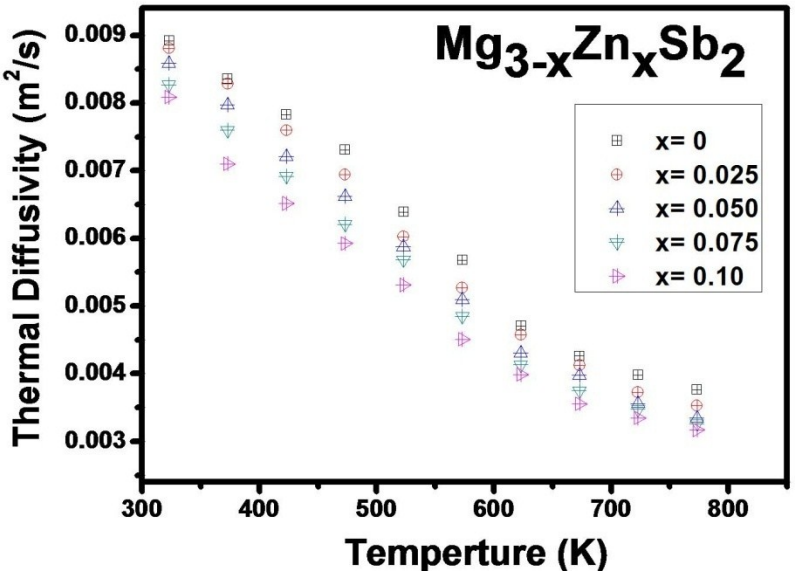

Figure S1: Temperature dependence of thermal diffusivity for $Mg_{3-x}Zn_x\ Sb_2$ ($0 \leq x \leq 0.1$).

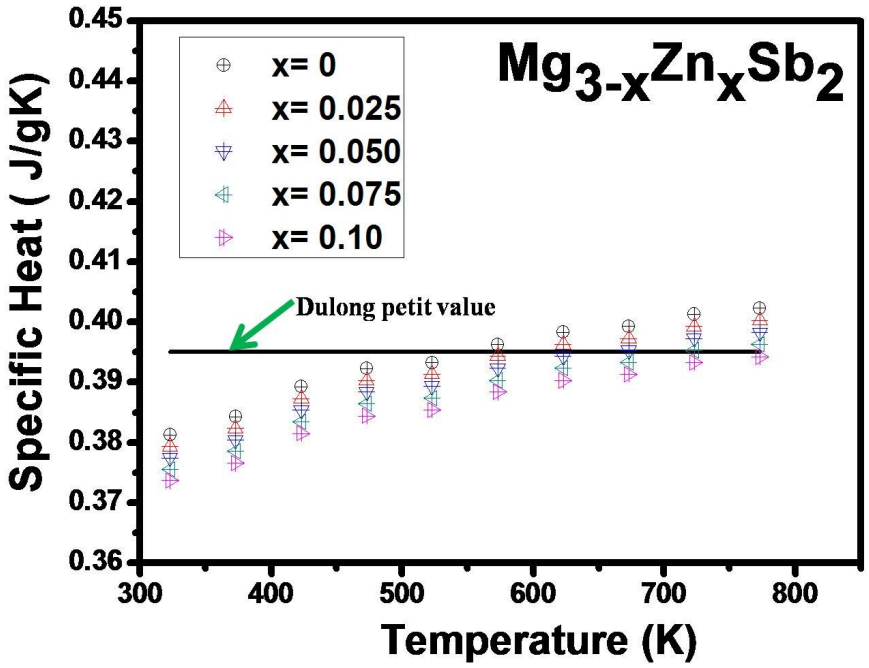

Figure S1: Temperature dependence of specific heat for $Mg_{3-x}Zn_x Sb_2$ ($0 \leq x \leq 0.1$).

Table T1. Density of $Mg_{3-x}Zn_xSb_2$ ($0 \leq x \leq 0.1$) materials

Compositions	Mg_3Sb_2	$Mg_{2.975}Zn_{0.025}Sb_2$	$Mg_{2.95}Zn_{0.050}Sb_2$	$Mg_{2.925}Zn_{0.075}Sb_2$	$Mg_{2.9}Zn_{0.10}Sb_2$
Density (g/cm^3)	3.93	3.90	3.96	3.94	3.89